



**15N25**

Preliminary

*Power MOSFET*

**15A, 250V N-CHANNEL  
POWER MOSFET**

■ DESCRIPTION

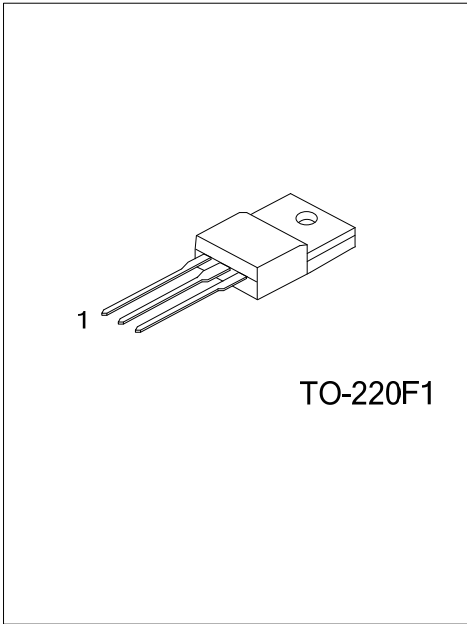
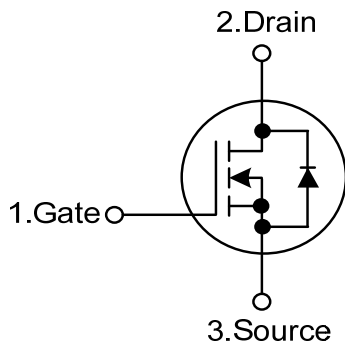
The UTC **15N25** is an N-channel enhancement MOSFET using UTC's advanced technology to provide the customers with perfect  $R_{DS(ON)}$ , high switching speed, high current capacity and low gate charge.

The UTC **15N25** is universally applied in low voltage such as automotive, high efficiency switching for DC/DC converters and DC motor control, etc.

■ FEATURES

- \*  $R_{DS(ON)} < 0.32\Omega$  @  $V_{GS}=10V, I_D=7.5A$
- \* Low Gate Charge (Typical 20nC)
- \* Low  $C_{RSS}$  (Typical 25pF)
- \* High Switching Speed

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
15N25L-TF1-T	15N25G-TF1-T	TO-220F1	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>15N25L-TF1-T</p> <p>(1)Packing Type (2)Package Type (3)Lead Free</p>	<p>(1) T: Tube, R: Tape Reel (2) TF1: TO-220F1 (3) L: Lead Free, G: Halogen Free</p>
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■ ABSOLUTE MAXIMUM RATINGS (unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	$V_{DSS}$	250	V
Gate-Source Voltage	$V_{GSS}$	$\pm 30$	V
Continuous Drain Current	Continuous	$I_D$	15
	Pulsed	$I_{DM}$	60
Single Pulsed Avalanche Current	$I_{AS}$	15	A
Single Pulsed Avalanche Energy	$E_{AS}$	340	mJ
Power Dissipation	$P_D$	83	W
Junction Temperature	$T_J$	+150	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-55 ~ +150	$^{\circ}\text{C}$
Note:	Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.		

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	110	$^{\circ}\text{C}/\text{W}$
Junction to Case	$\theta_{JC}$	1.5	$^{\circ}\text{C}/\text{W}$

■ ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	250			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=250\text{V}, V_{GS}=0\text{V}$			1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{GSS}$	Forward			+100	nA
		Reverse			-100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2		4	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10\text{V}, I_D=7.5\text{A}$		0.29	0.32	$\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1.0\text{MHz}$		830	1080	pF
Output Capacitance	$C_{OSS}$			200	260	pF
Reverse Transfer Capacitance	$C_{RSS}$			25	33	pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge	$Q_G$	$V_{GS}=10\text{V}, V_{DD}=50\text{V}, I_D=1.3\text{A}$		67	75	nC
Gate to Source Charge	$Q_{GS}$			15		nC
Gate to Drain Charge	$Q_{GD}$			18		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=30\text{V}, I_D=0.5\text{A}, R_G=25\Omega,$ $V_{GS}=10\text{V}, R_L=30\Omega$		40	50	ns
Rise Time	$t_R$			50	60	ns
Turn-OFF Delay Time	$t_{D(OFF)}$			130	140	ns
Fall-Time	$t_F$			50	65	ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Body-Diode Continuous Current	$I_S$				15	A
Maximum Body-Diode Pulsed Current	$I_{SM}$				60	A
Drain-Source Diode Forward Voltage	$V_{SD}$	$I_S=15\text{A}, V_{GS}=0\text{V}$			1.5	V

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